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|  | <h2 style="color: red;">IPD70N03S4L-04</h2> | |
| | Hersteller-Teilenummer: | IPD70N03S4L-04 |
|  | Hersteller / Marke: | International Rectifier (Infineon Technologies) |
| | Teil der Beschreibung: | IPD70N03S4L-04 Infineon Technologies |
| Datenblätter: |  IPD70N03S4L-04.pdf | |
| RoHs Status: | Bleifrei / RoHS-konform | |
| Lagerzustand: | New original, 137119 pcs Stock Available. | |
| Liefern von: | Hong Kong | |
| Versandweg: | DHL/Fedex/TNT/UPS/EMS | |
| <p>Image may be representation. See specs for product details.</p> | | |

Spezifikationen

| | |
|---|---|
| Teilenummer | IPD70N03S4L-04 |
| Hersteller | International Rectifier (Infineon Technologies) |
| Beschreibung | IPD70N03S4L-04 Infineon Technologies |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 137119 pcs Stock |
| Serie | OptiMOS™ |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Surface Mount |
| Verpackung / Gehäuse | TO-252-3, DPak (2 Leads + Tab), SC-63 |
| Supplier Device-Gehäuse | PG-TO252-3 |
| Verlustleistung (max) | 68W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 30V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 °C | 70A (Tc) |
| Rds On (Max) @ Id, Vgs | 4.3 mOhm @ 70A, 10V |
| VGS (th) (Max) @ Id | 2.2V @ 30µA |
| Gate Charge (Qg) (Max) @ Vgs | 48nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 3300pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 4.5V, 10V |
| Vgs (Max) | ±16V |
| Verpackung | Tape & Reel (TR) |

IPD70N03S4L-04 ist neu im Original, Suche IPD70N03S4L-04 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IPD70N03S4L-04 International Rectifier (Infineon Technologies) mit Garantie und Vertrauen. Anfrage IPD70N03S4L-04: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|--|---|---|---|
|  <p>IPD70N03S4L04ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 30V 70A TO252-3</p> |  <p>IPD65R950C6 INFINEO IPD65R950C6 INFINEO</p> |  <p>IPD70N10S312ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH 100V 70A TO252-3</p> |  <p>IPD65R950CFD infineo IPD65R950CFD infineo</p> |
|  <p>IPD70N04S3-07 International Rectifier (Infineon Technologies) MOSFET N-CH 40V 82A TO252-3</p> |  <p>IPD70N03S4L04XT INFINEON IPD70N03S4L04XT INFINEON</p> |  <p>IPD65R950C6ATMA1 International Rectifier (Infineon Technologies) MOSFET N-CH TO252-3</p> |  <p>IPD70N10S3-12 VBsemi IPD70N10S3-12 VBsemi</p> |

heiße Teile

Mehr

- | | | | | |
|-------------------|------------------|------------------|------------------|-----------------|
| ⊗ IPD60R400CE | ↔ IPD60R450E6 | ⇒ IPD60R520C6 | D IPD60R520CP | ⇒ IPD60R600C6 |
| ⊣ IPD60R600CP | ⊗ IPD60R600E6 | D IPD60R600P6 | ⇒ IPD60R750E6 | ⇒ IPD60R800CE |
| ⊗ IPD60R950C6 | ⊣ IPD640N06LG | ⊗ IPD64CN10NG | ↔ IPD65R1K4C6 | ⇒ IPD65R250C6 |
| D IPD65R250E6 | ⊗ IPD65R380C6 | ⊣ IPD65R380E6 | ⊗ IPD65R420CFD | ⇒ IPD65R420CFDA |
| ⇒ IPD65R600C6 | ↔ IPD65R600E6 | ⊗ IPD65R660CFD | ⊣ IPD65R950C6 | ⇒ IPD65R950CFD |
| ↔ IPD70N03S4L04XT | ⇒ IPD70N04S3-07 | D IPD70N10S3-12 | ⊗ IPD70N10S3L-12 | ⊣ IPD70P04P4-09 |
| ⊗ IPD70P04P4L-08 | D IPD75N04S4-06 | ⇒ IPD78CN10NG | ↔ IPD800N06NG | ⇒ IPD80N04S3-06 |
| ⊣ IPD80N04S3-06B | ⊗ IPD80N06S3-09 | ↔ IPD80P03P4L-07 | ⇒ IPD80R1K0CE | ⇒ IPD80R1K4CE |
| ⊗ IPD85P04P4L-06 | ⊣ IPD90N03S4L-02 | ⊗ IPD90N03S4L-03 | D IPD90N04S03-04 | ⇒ IPD90N04S3-04 |
| ↔ IPD90N04S3-H4 | ⊗ IPD90N04S4-02 | ⊣ IPD90N04S4-03 | ⊗ IPD90N04S4-04 | ⇒ IPD90N04S4-05 |

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